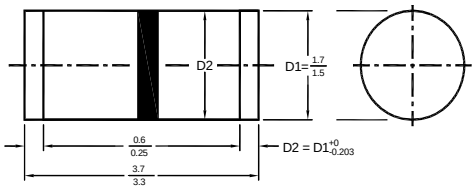
LMDB3

Silicon Bidirectional Trigger Diodes

These diacs are intended for use in thyristor phase control, circuits for lamp-dimming, universal-motor speed controls, and heat controls.



MiniMELF (DO-213AA) Plastic Package
Dimensions in millimeters

Absolute Maximum Ratings (T_a = 25 °C)

Parameter	Symbol	Value	Unit
Power Dissipation (T_a = 65 °C)	P_{tot}	150	mW
Repetitive Peak On-state Current (tp = 20 µs, f = 100 Hz)	I_{TRM}	2	A
Operating Junction and Storage Temperature Range	T_j, T_{stg}	- 40 to + 125	°C

Characteristics at T_a = 25 °C

Parameter	Symbol	Min.	Max.	Unit
Breakover Voltage at C = 22 nF, see diagram 1	V_{BO}	28	36	V
Breakover Voltage Symmetry at C = 22 nF, see diagram 1	$[\|+V_{BO}\|-\|-V_{BO}\|]$	-	3	V
Dynamic Breakover Voltage at $\Delta I = [I_{BO}$ to I_F = 10 mA]	$\|\ \Delta V \pm \|$	5	-	V
Output Voltage See diagram 2	V_O	5	-	V
Breakover Current at C = 22 nF	I_{BO}	-	50	µA
Leakage Current at V_B = 0.5 V_{BO} max	I_B	-	10	µA
Rise Time See diagram 3	t_r	-	2	µs

Diagram 1: Current-voltage characteristics

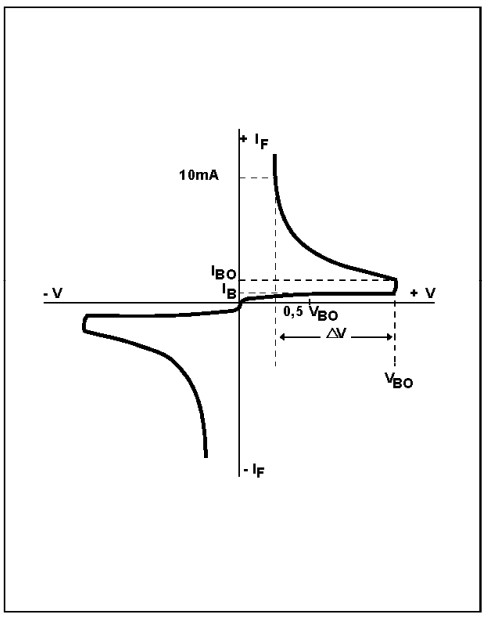


Diagram 2: Test circuit for output voltage

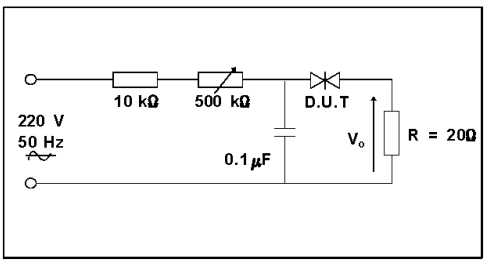


Diagram 3: Test circuit see diagram 2.
Adjust R for Ip=0.5A

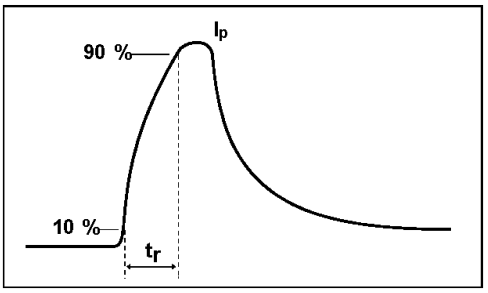


Fig. 1: Power dissipation versus ambient temperature (maximum values)

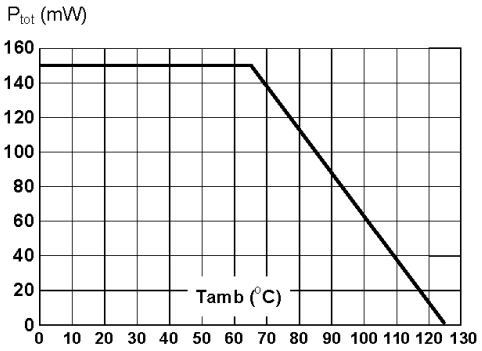


Fig. 2: Relative variation of V_{BO} versus junction temperature (typical values)

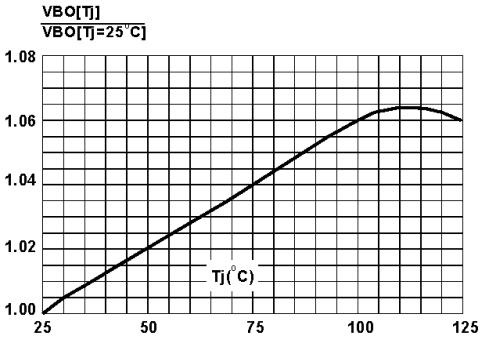


Fig. 3: Peak pulse current versus pulse duration (maximum values)